

TRIAC(Surface Mount Device / Non-isolated)

TMG8CQ60H

(T_j=150°C)

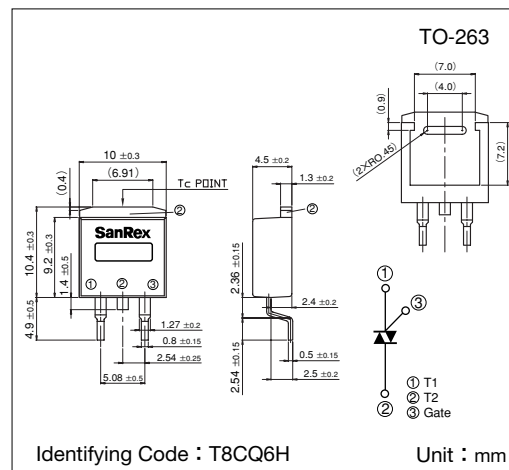
SanRex Triac TMG8CQ60H is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

Features

- I_{T(RMS)}=8A
- High Surge Current
- Low Voltage Drop
- Lead-Free Package



Maximum Ratings

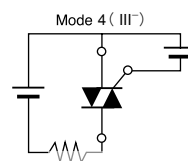
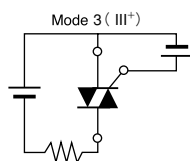
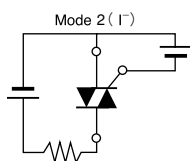
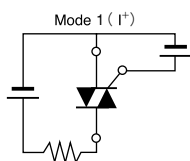
(T_j=25°C unless otherwise specified)

Symbol	Item	Reference	Ratings	Unit
V _{DRM}	Repetitive Peak Off-State Voltage		600	V
I _{T(RMS)}	R.M.S. On-State Current	T _c =130°C	8	A
I _{TSM}	Surge On-State Current	One cycle, 50Hz/60Hz, Peak value non-repetitive	80/88	A
I ² t	I ² t (for fusing)		32	A ² S
P _{GM}	Peak Gate Power Dissipation		5	W
P _{G(AV)}	Average Gate Power Dissipation		0.5	W
I _{GM}	Peak Gate Current		2	A
V _{GM}	Peak Gate Voltage		10	V
T _j	Operating Junction Temperature		-40~+150	°C
T _{stg}	Storage Temperature		-40~+150	°C
	Mass		1.2	g

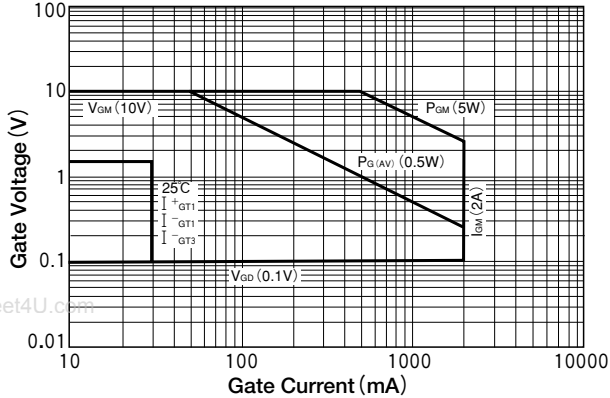
Electrical Characteristics

Symbol	Item		Reference	Ratings			Unit
				Min.	Typ.	Max.	
IDRM	Repetitive Peak Off-State Current		VD=VDRM, Single phase, half wave, Tj=150°C			2	mA
VTM	Peak On-State Voltage		IT=12A, Inst. measurement			1.4	V
I _{GT1} ⁺	1	Gate Trigger Current	VD=6V, RL=10 Ω			30	mA
I _{GT1} [−]	2					30	
I _{GT3} ⁺	3					—	
I _{GT3} [−]	4					30	
V _{GT1} ⁺	1	Gate Trigger Voltage				1.5	V
V _{GT1} [−]	2					1.5	
V _{GT3} ⁺	3					—	
V _{GT3} [−]	4					1.5	
VGD	Non-Trigger Gate Voltage		Tj=150°C, VD=1/2VDRM	0.1			V
(dv/dt)c	Critical Rate of Rise of Off-State Voltage at Commutation		Tj=150°C, [di/dt)c=−4A/ms, VD=2/3VDRM	5			V/μs
IH	Holding Current				15		mA
Rth	Thermal Resistance		Junction to case			2.0	°C/W

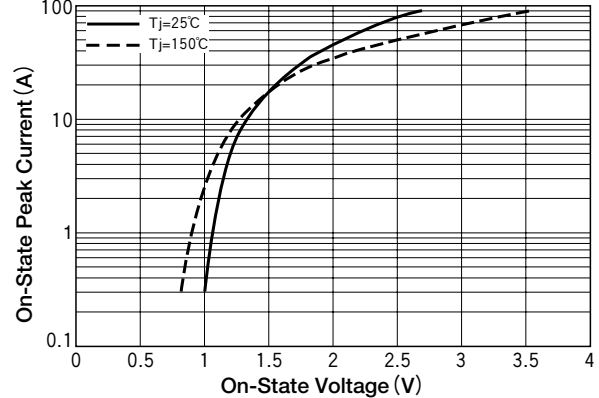
Trigger mode of the triac



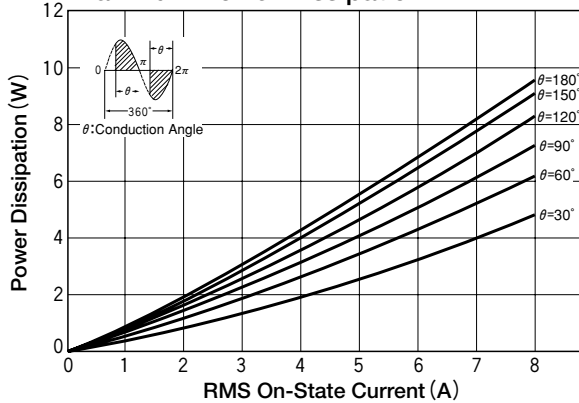
Gate Characteristics



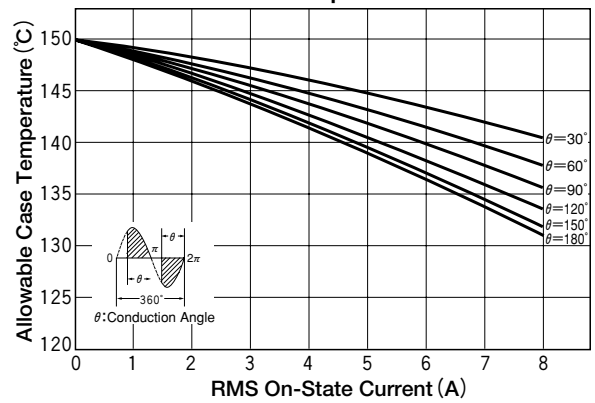
On-State Characteristics (MAX)



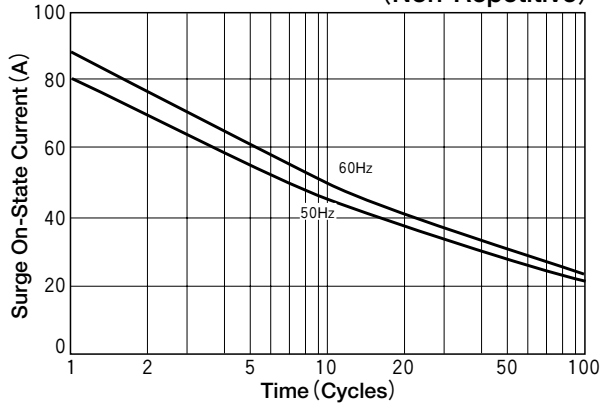
RMS On-State Current vs Maximum Power Dissipation



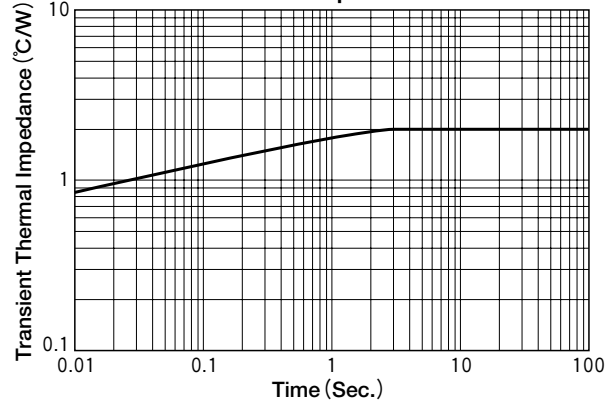
RMS On-State vs Allowable Case Temperature



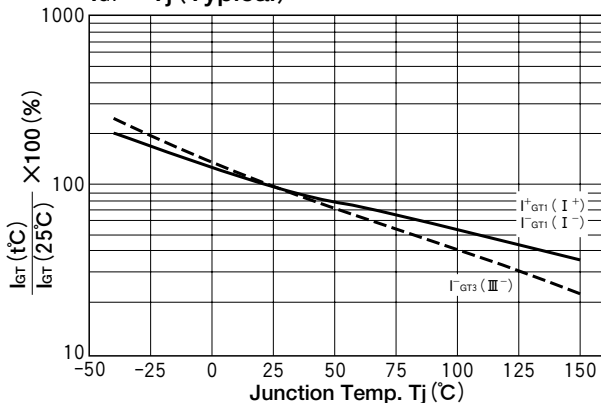
Surge On-State Current Rating (Non-Repetitive)



Transient Thermal Impedance



$I_{GT} - T_J$ (Typical)



$V_{GT} - T_J$ (Typical)

